





#### MMSZ5221B-MMSZ5259B ZENER DIODES



#### **Features**

- Planar Die Construction
- 500mW Power Dissipation
- 2.4V- 39V Standoff Voltage
- 5% Nominal Zener Voltage
- Designed for Surface Mount Application
- Plastic Material-UL Recognition Flammability Classification 94V-O
- This is a Halogen Free Device
- "-A" is an AEC-Q101 qualified device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Mechanical Data**

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202,

Method 208

- Polarity: Cathode Band
- Weight: 0.01 grams(approx)

#### Maximum Ratings @TA=25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Power Dissipation (Note 1)	P <sub>D</sub>	500	mW
Forward Voltage (Note 2) @ I <sub>F</sub> = 10mA	VF	0.9	V
Typical Thermal resistance junction to Ambient Air	Reja	357	°C/W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 to 150	°C

Notes: 1. Device mounted on ceramic PCB; 7.6 mm x 9.4 mm x 0.87 mm with pad areas 25 mm<sup>2</sup>.

2. Tested with pulses, Tp≤1.0ms.









## Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Туре	Code	Zener Voltage Range (Note 2)			Maximum Zener Impedance (Note 4)			Maximum Reverse Current		
Number			Vz@lzt		I <sub>ZT</sub>	Zzt@lzt	Zzk@lzk	I <sub>ZK</sub>	I <sub>R</sub>	V <sub>R</sub>
		Nom(V)	Min(V)	Max(V)	mA	٥	)	mA	uA	V
MMSZ5221B	C1	2.4	2.28	2.52	20	30	1200	0.25	100	1.0
MMSZ5223B	C3	2.7	2.57	2.84	20	30	1300	0.25	75	1.0
MMSZ5225B	C5	3.0	2.85	3.15	20	30	1600	0.25	50	1.0
MMSZ5226B	G1	3.3	3.14	3.47	20	28	1600	0.25	25	1.0
MMSZ5227B	G2	3.6	3.42	3.78	20	24	1700	0.25	15	1.0
MMSZ5228B	G3	3.9	3.71	4.10	20	23	1900	0.25	10	1.0
MMSZ5229B	G4	4.3	4.09	4.52	20	22	2000	0.25	5	1.0
MMSZ5230B	G5	4.7	4.47	4.94	20	19	1900	0.25	5	2.0
MMSZ5231B	E1	5.1	4.85	5.36	20	17	1600	0.25	5	2.0
MMSZ5232B	E2	5.6	5.32	5.88	20	11	1600	0.25	5	3.0
MMSZ5233B	E3	6.0	5.70	6.30	20	7	1600	0.25	5	3.5
MMSZ5234B	E4	6.2	5.89	6.51	20	7	1000	0.25	5	4.0
MMSZ5235B	E5	6.8	6.46	7.14	20	5	750	0.25	3	5.0
MMSZ5236B	F1	7.5	7.13	7.88	20	6	500	0.25	3	6.0
MMSZ5237B	F2	8.2	7.79	8.61	20	8	500	0.25	3	6.5
MMSZ5238B	F3	8.7	8.27	9.14	20	8	600	0.25	3	6.5
MMSZ5239B	F4	9.1	8.65	9.56	20	10	600	0.25	3	7.0
MMSZ5240B	F5	10	9.50	10.50	20	17	600	0.25	3	8.0
MMSZ5241B	H1	11	10.45	11.55	20	22	600	0.25	2.0	8.4
MMSZ5242B	H2	12	11.40	12.60	20	30	600	0.25	1.0	9.1
MMSZ5243B	НЗ	13	12.35	13.65	9.5	13	600	0.25	0.5	9.9
MMSZ5244B	H4	14	13.30	14.70	9.0	15	600	0.25	0.1	10
MMSZ5245B	H5	15	14.25	15.75	8.5	16	600	0.25	0.1	11
MMSZ5246B	J1	16	15.20	16.80	7.8	17	600	0.25	0.1	12
MMSZ5248B	J3	18	17.10	18.90	7.0	21	600	0.25	0.1	14
MMSZ5250B	J5	20	19.00	21.00	6.2	25	600	0.25	0.1	15
MMSZ5251B	K1	22	20.90	23.10	5.6	29	600	0.25	0.1	17
MMSZ5252B	K2	24	22.80	25.20	5.2	33	600	0.25	0.1	18
MMSZ5253B	КЗ	25	23.75	26.25	5.0	35	600	0.25	0.1	19
MMSZ5254B	K4	27	25.65	28.35	5.0	41	600	0.25	0.1	21
MMSZ5255B	K5	28	26.60	29.40	4.5	44	600	0.25	0.1	21
MMSZ5256B	M1	30	28.50	31.50	4.2	49	600	0.25	0.1	23
MMSZ5257B	M2	33	31.35	34.65	3.8	58	700	0.25	0.1	25
MMSZ5258B	МЗ	36	34.20	37.80	3.4	70	700	0.25	0.1	27
MMSZ5259B	M4	39	37.05	40.95	3.2	80	800	0.25	0.1	30

<sup>•</sup> China - Germany - Korea - Singapore - United States • http://www.smc-diodes.com - sales@ smc-diodes.com •







# **Ratings and Characteristics Curves** Zener Characteristics (11 V to 39 V) T\_=25°C T<sub>a</sub> = 25°C Pulsed I, ZENER CURRENT (mA) L, ZENER CURRENT (mA) V<sub>z</sub>, ZENER VOLTAGE (V) V<sub>z</sub>, ZENER VOLTAGE (V) Typical Leakage Current Temperature Coefficients TYPICAL T\_VALUES TEMPERATURE COEFFICIENT (mV/'C) , LEAKAGE CURRENT (uA) $V_z$ , NOMINAL ZENER VOLTAGE (V) V<sub>z</sub>, NOMINAL ZENER VOLTAGE (V) Effect of Zener Voltage on Zener Impedance Typical Capacitance T=25°C f=1kHz Z<sub>zz</sub>, DYNAMIC IMPEDANCE(Ω) C, CAPACITANCE (pF) BIAS AT 50% OF V<sub>z</sub> NOM V<sub>z</sub>, NOMINAL ZENER VOLTAGE (V) V<sub>z</sub>, NOMINAL ZENER VOLTAGE (V) Power Derating Curve (MM) ď POWER DISSIPATION

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AMBIENTTEMPERATURE T, (°C)

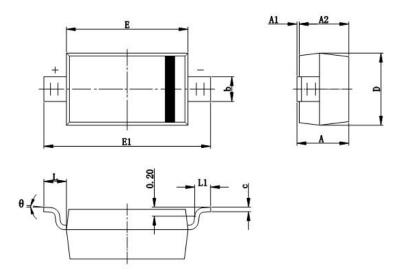
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## **Mechanical Dimensions SOD-123**



CVMDOL	Millim	neters	Inches		
SYMBOL	MIN. MAX.		MIN.	MAX.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.450	0.650	0.018	0.026	
С	0.080	0.150	0.003	0.006	
D	1.500	1.700	0.059	0.067	
E	2.600	2.800	0.102	0.110	
E1	3.550	3.850	0.140	0.152	
L	0.500	REF.	0.020 REF.		
L1	0.250	0.450	0.010	0.018	
θ	0°	8°	0°	8°	

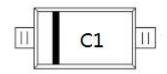
Note: If date code is before 2016 year, please contact with factory about marking.

## **Ordering Information**

Device	Package	Shipping
MMSZ5221B- MMSZ5259B	SOD-123	3000pcs / reel
MMSZ5221BTR- MMSZ5259BTR	SOD-123	3000pcs / reel

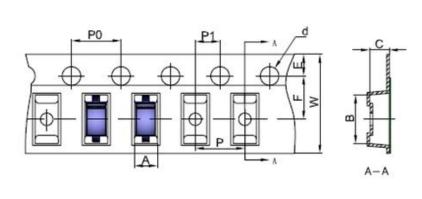
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



C1 = Marking code

## **Carrier Tape Specification SOD-123**



SYMBOL	Millimeters				
STWIBUL	Min.	Max.			
Α	1.80	1.90			
В	3.89	3.99			
С	1.52	1.62			
d	1.45	1.65			
Е	1.65	1.85			
F	3.40	3.60			
Р	3.90	4.10			
P0	3.90	4.10			
P1	1.90	2.10			
W	7.90	8.30			

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#### MMSZ5221B-MMSZ5259B



#### Technical Data Data Sheet N0205, Rev. B





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